

QSI LASER DIODE

SPECIFICATIONS FOR APPROVAL

Customer :

Model : QL80R4S-A/B/C/D/E-Z

Tentative

Signature of Approval

Approved by _____

Checked by _____

Issued by _____

Approval by Customer



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QL80R4S-A/B/C/D/E-Z

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Laser Diode

Quantum Semiconductor International Co., Ltd.

Ver.2 Nov. 2006

◆ OVERVIEW

QL80R4S-A/B/C/D/E-Z is a MOCVD grown 808nm band laser diode with quantum well structure. It's an attractive light source, with a typical light output power of 200mW for optoelectronic devices such as solid state laser pumping and medical use.

◆ APPLICATION

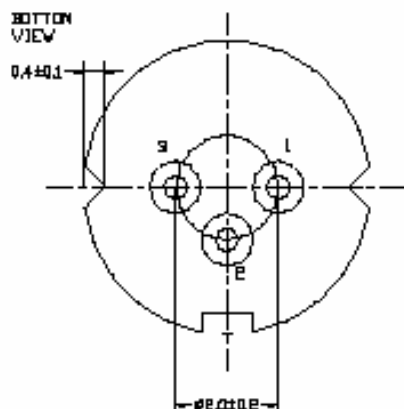
- Solid State Laser Pumping
- Medical Use
- Industrial Use

◆ FEATURES

- Wavelength : $\lambda_p = 808 \text{ nm}$
- Optical Output Power : 200mW (CW)
- Package Type : TO-18 ($\phi 5.6\text{mm}$)
- Polarization : TE (Electric Field Parallel to the Junction Plane)

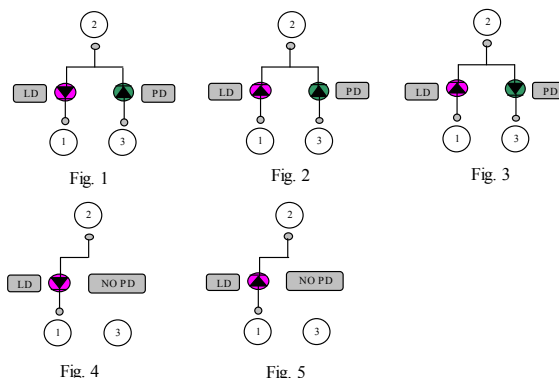
◆ ELECTRICAL CONNECTION

Bottom View



Pin Configuration

A	LD cathode, PD anode (Fig. 1)	QL80R4S-A
B	LD, PD anode (Fig. 2)	QL80R4S-B
C	LD anode, PD cathode (Fig. 3)	QL80R4S-C
D	LD cathode, No PD (Fig. 4)	QL80R4S-D
E	LD anode, No PD (Fig. 5)	QL80R4S-E



Tentative

◆ **ABSOLUTE MAXIMUM RATING at Tc=25°C**

Items	Symbols	Values	Unit
Optical Output Power	P	200	mW
Laser Diode Reverse Voltage	V	2	V
Photo Diode Reverse Voltage	V	30	V
Operating Temperature	Topr	-10 ~ +40	°C
Storage Temperature	Tstg	-40 ~ +85	°C

◆ **ELECTRICAL and OPTICAL CHARACTERISTICS at Tc=25°C ¹⁾²⁾**

Items	Symbols	Min.	Typ.	Max.	Unit	Condition
Optical Output Power	P _o	-	200	-	mW	-
Threshold Current	I _{th}	-	60	80	mA	-
Operating Current	I _{op}	-	250	280	mA	P _o =200mW
Operating Voltage	V _{op}	-	1.9	2.5	V	P _o =200mW
Lasing Wavelength	λ _p	803	808	813	nm	P _o =200mW
Beam Divergence ³⁾	θ	-	8	12	deg	P _o =200mW
	θ ⊥	-	35	45	deg	P _o =200mW
Beam Angle	Δθ	-	-	±3	deg	P _o =200mW
	Δθ ⊥	-	-	±3	deg	P _o =200mW
Monitor Current	I _m	-	0.5	1.5	mA	P _o =200mW
Polarization	TE mode					
Optical Distance	ΔX, ΔY, ΔZ	-	-	±60	μm	-

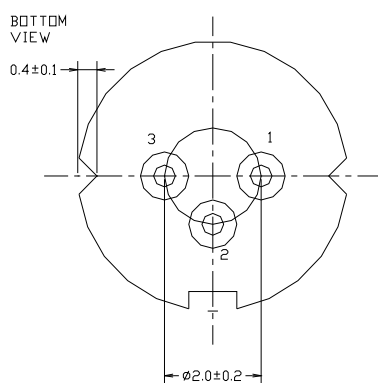
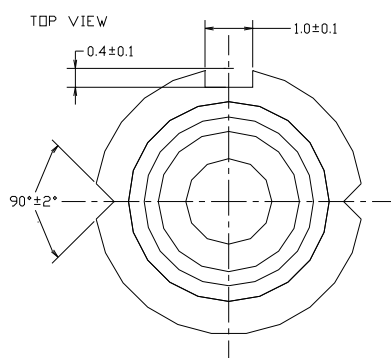
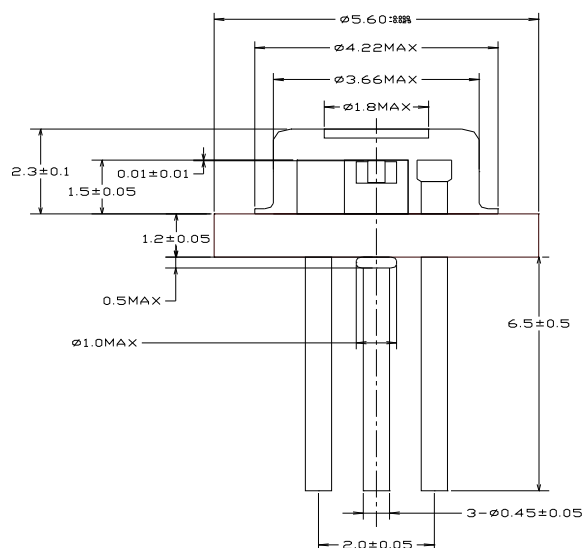
1) Initial Values 2) All above values are evaluated with QSI's measuring apparatus

3) Full Width at Half Maximum

NOTICE : QL80R4S-A/B/C/D/E-Z to be operated on APC circuit.

The above product specifications are subject to change without notice.

◆ PACKAGE DIMENSION



◆ PACKING

